

# EE 232: Lightwave Devices

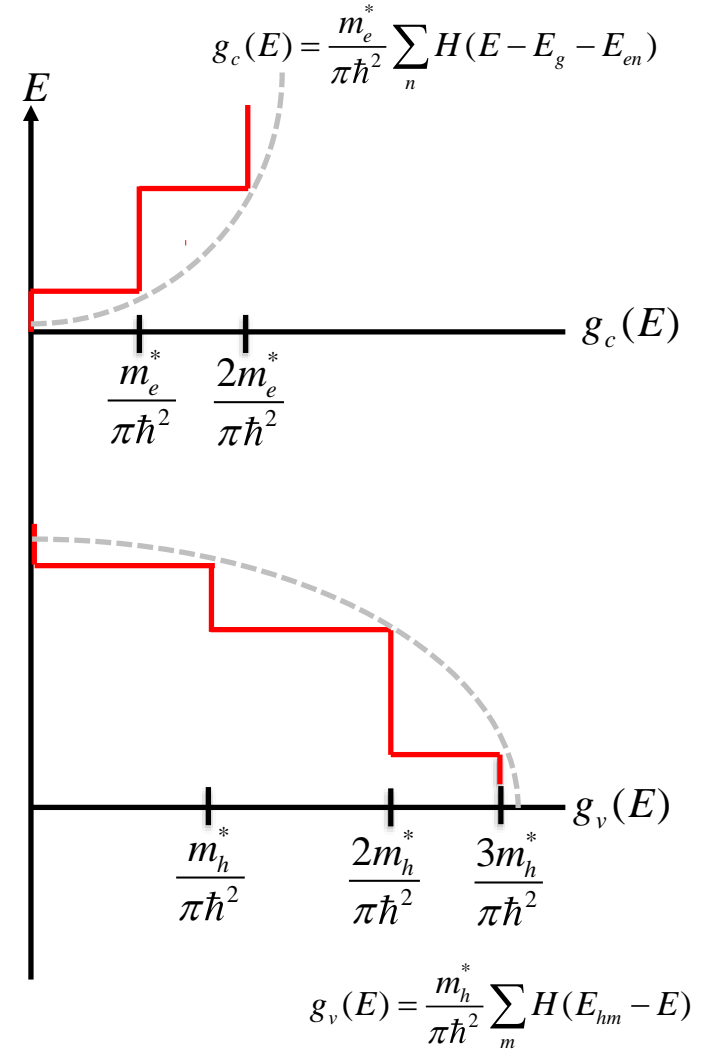
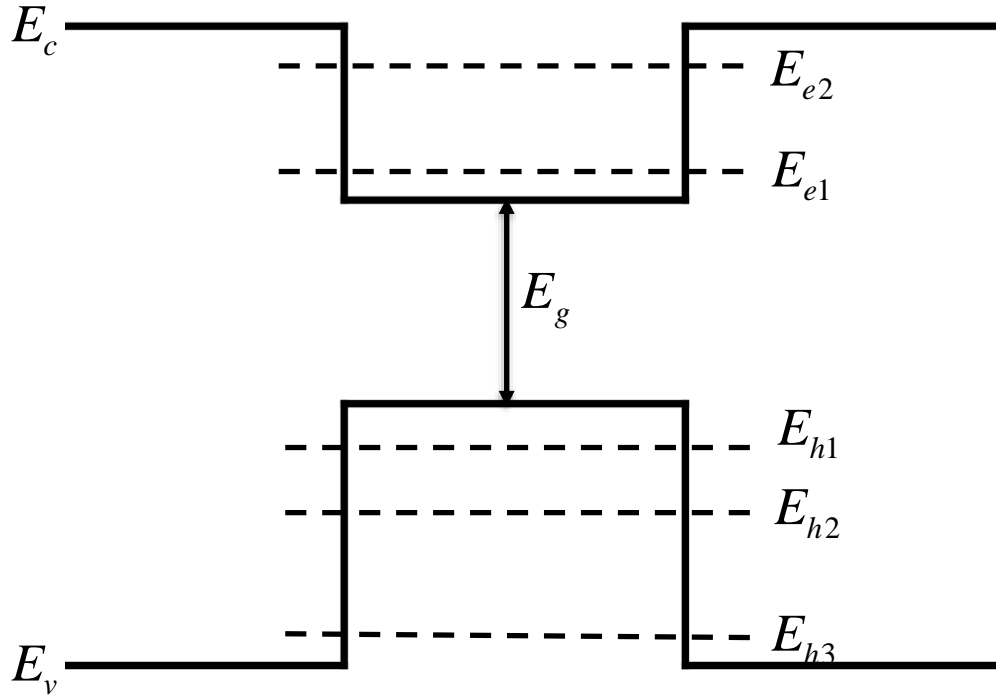
## Lecture #10 – Absorption in quantum wells

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# Semiconductor quantum well



# Absorption coefficient

$$\alpha = C_0 \frac{2}{V} \sum_{k_z} \sum_{k_t} |\hat{e} \cdot \mathbf{p}_{cv}|^2 \delta(E_e - E_h - \hbar\omega) (f_v - f_c)$$

$$2 \sum_{k_t} \rightarrow A \int_{-\infty}^{\infty} \frac{2d^2k_t}{(2\pi)^2} = A \int_{-\infty}^{\infty} \frac{2(2\pi k_t)dk_t}{(2\pi)^2} = A \int_{-\infty}^{\infty} \frac{k_t dk_t}{\pi}$$

Note that here,

$$\mathbf{p}_{cv} = \langle \psi_c | \mathbf{p} | \psi_v \rangle$$

$\psi_c$  and  $\psi_v$  are bloch states

$$E_e = E_g + E_{en} + \frac{\hbar^2 k_t^2}{2m_e^*}$$

$$E_h = E_{hm} - \frac{\hbar^2 k_t^2}{2m_h^*}$$

$$E_e - E_h = E_{hm}^{en} + \frac{\hbar^2 k_t^2}{2m_r^*} \quad \text{where} \quad \frac{1}{m_r^*} = \frac{1}{m_e^*} + \frac{1}{m_h^*}$$

$$\text{Let } E = \frac{\hbar^2 k_t^2}{2m_r^*} \rightarrow k_t = \sqrt{\frac{2m_r^* E}{\hbar^2}} \quad \frac{dk_t}{dE} = \frac{m_r^*}{\hbar^2} \sqrt{\frac{\hbar^2}{2m_r^* E}}$$

# Absorption coefficient

$$\begin{aligned}
 2 \sum_{k_t} &\rightarrow A \int_{-\infty}^{\infty} \frac{2d^2k_t}{(2\pi)^2} = A \int_{-\infty}^{\infty} \frac{2(2\pi k_t)dk_t}{(2\pi)^2} = A \int_{-\infty}^{\infty} \frac{k_t dk_t}{\pi} \\
 &= A \int_0^{\infty} \frac{m_r^*}{\pi \hbar^2} dE \\
 &= A \int_{-\infty}^{\infty} \frac{m_r^*}{\pi \hbar^2} H(E) dE = A \int_{-\infty}^{\infty} \rho_{r,2D} H(E) dE
 \end{aligned}$$

$$\begin{aligned}
 \alpha &= C_0 \frac{2}{V} \sum_{k_z} \sum_{k_t} |\hat{e} \cdot \mathbf{p}_{cv}|^2 \delta(E_e - E_h - \hbar\omega) (f_v - f_c) \\
 &= C_0 \frac{1}{L_z} \sum_{n,m} \int_{-\infty}^{\infty} |\hat{e} \cdot \mathbf{p}_{cv}|^2 \rho_{r,2D} H(E) \delta(E + E_{hm}^{en} - \hbar\omega) (f_v(E) - f_c(E)) dE \\
 &= C_0 \frac{1}{L_z} \sum_{n,m} |\hat{e} \cdot \mathbf{p}_{cv}|^2 \rho_{r,2D} H(\hbar\omega - E_{hm}^{en}) \left[ f_v(E = \hbar\omega - E_{hm}^{en}) - f_c(E = \hbar\omega - E_{hm}^{en}) \right]
 \end{aligned}$$

$$\alpha(\hbar\omega) = C_0 \frac{1}{L_z} \sum_{n,m} |\hat{e} \cdot \mathbf{p}_{cv}|^2 \rho_{r,2D} H(\hbar\omega - E_{hm}^{en}) \left[ f_v(E = \hbar\omega - E_{hm}^{en}) - f_c(E = \hbar\omega - E_{hm}^{en}) \right]$$

# Absorption with inclusion of other valence bands

$$\alpha_{hh}(\hbar\omega) = C_0 \frac{1}{L_z} \sum_{n,m} |\hat{e} \cdot \mathbf{p}_{cv,hh}|^2 \rho_{r,hh,2D} H(\hbar\omega - E_{hm}^{en}) \left[ f_v(E = \hbar\omega - E_{hm}^{en}) - f_c(E = \hbar\omega - E_{hm}^{en}) \right]$$

(heavy hole)

$$\alpha_{lh}(\hbar\omega) = C_0 \frac{1}{L_z} \sum_{n,m} \underbrace{|\hat{e} \cdot \mathbf{p}_{cv,lh}|^2 \rho_{r,lh,2D} H(\hbar\omega - E_{hm}^{en})}_{\text{Valence band dependent}} \left[ f_v(E = \hbar\omega - E_{hm}^{en}) - f_c(E = \hbar\omega - E_{hm}^{en}) \right]$$

(light hole)

↑
↑  
 Valence band dependent      Valence band dependent

$$\alpha(\hbar\omega) = \alpha_{lh} + \alpha_{hh}$$

Total absorption coefficient is the summation of absorption between the conduction and each valence band.

# Fermi factor

$$f_c(E_e) = \frac{1}{1 + \exp[(E_e - F_c) / kT]}$$

$$f_v(E_h) = \frac{1}{1 + \exp[(E_h - F_v) / kT]}$$

We need a change of variables from  $E_e, E_h \rightarrow E = \frac{\hbar^2 k^2}{2m_r^*}$

Because of the delta function,  $E = \hbar\omega - E_{hm}^{en} = \frac{\hbar^2 k^2}{2m_r^*} \rightarrow k = \sqrt{\frac{2m_r^*}{\hbar^2} (\hbar\omega - E_{hm}^{en})}$

$$\begin{aligned} E_e &= E_g + E_{en} + \frac{\hbar^2 k^2}{2m_e^*} \\ &= E_g + E_{en} + (\hbar\omega - E_{hm}^{en}) \frac{m_r^*}{m_e^*} \end{aligned}$$

$$\begin{aligned} E_h &= E_{hm} - \frac{\hbar^2 k^2}{2m_h^*} \\ &= E_{hm} - (\hbar\omega - E_{hm}^{en}) \left( \frac{m_r^*}{m_h^*} \right) \end{aligned}$$

$$f_c(\hbar\omega) = \frac{1}{1 + \exp\left[ (E_g + E_{en} + (\hbar\omega - E_{hm}^{en}) m_r^* / m_e^* - F_c) / kT \right]}$$

$$f_v(\hbar\omega) = \frac{1}{1 + \exp\left[ (E_{hm} - (\hbar\omega - E_{hm}^{en}) m_r^* / m_h^* - F_v) / kT \right]}$$

# Optical matrix element

Optical matrix element

$$\hat{H}_{cv} = \langle \psi_c | \frac{-qA_0 e^{i\mathbf{k}_{op} \cdot \mathbf{r}}}{2m_0} \hat{\mathbf{e}} \cdot \mathbf{p} | \psi_v \rangle$$

Bloch states

$$\psi_c = u_c(\mathbf{r}) \frac{e^{i\mathbf{k}_c \cdot \mathbf{r}}}{\sqrt{A}} \phi_n(z) \quad \psi_v = u_v(\mathbf{r}) \frac{e^{i\mathbf{k}_v \cdot \mathbf{r}}}{\sqrt{A}} g_m(z)$$

↑  
periodic  
with lattice

↑  
envelope function

$$\begin{aligned} \hat{H}_{cv} &= \left\langle u_c(\mathbf{r}) \frac{e^{i\mathbf{k}_c \cdot \mathbf{r}}}{\sqrt{A}} \phi_n(z) \left| \frac{-qA_0 e^{i\mathbf{k}_{op} \cdot \mathbf{r}}}{2m_0} \hat{\mathbf{e}} \cdot \mathbf{p} \right| u_v(\mathbf{r}) \frac{e^{i\mathbf{k}_v \cdot \mathbf{r}}}{\sqrt{A}} g_m(z) \right\rangle \\ &= \int u_c^*(\mathbf{r}) \frac{e^{-i\mathbf{k}_c \cdot \mathbf{r}}}{\sqrt{A}} \phi_n^*(z) \frac{-qA_0 e^{i\mathbf{k}_{op} \cdot \mathbf{r}}}{2m_0} \hat{\mathbf{e}} \cdot \mathbf{p} u_v(\mathbf{r}) \frac{e^{i\mathbf{k}_v \cdot \mathbf{r}}}{\sqrt{A}} g_m(z) d^3\mathbf{r} \end{aligned}$$

# Optical matrix element

$$\begin{aligned}
 \hat{H}_{cv} &= \int u_c^*(\mathbf{r}) \frac{e^{-i\mathbf{k}_c \cdot \mathbf{r}}}{\sqrt{A}} \phi_n^*(z) \frac{-qA_0 e^{i\mathbf{k}_{op} \cdot \mathbf{r}}}{2m_0} \hat{\mathbf{e}} \cdot \mathbf{p} u_v(\mathbf{r}) \frac{e^{i\mathbf{k}_v \cdot \mathbf{r}}}{\sqrt{A}} g_m(z) d^3\mathbf{r} \\
 &= \frac{-qA_0}{2m_0} \hat{\mathbf{e}} \cdot \int_V e^{i(-\mathbf{k}_c + \mathbf{k}_v + \mathbf{k}_{op}) \cdot \mathbf{r}} \phi_n^*(z) g_m(z) \frac{d^3\mathbf{r}}{A} \int_{\Omega} u_c^*(\mathbf{r}) (-i\hbar \nabla) u_v(\mathbf{r}) \frac{d^3\mathbf{r}}{\Omega} \\
 &= \frac{-qA_0}{2m_0} \hat{\mathbf{e}} \cdot \mathbf{p}_{cv} \int_V e^{i(-\mathbf{k}_c + \mathbf{k}_v + \mathbf{k}_{op}) \cdot \mathbf{r}} \phi_n^*(z) g_m(z) \frac{d^3\mathbf{r}}{A} \\
 &= \frac{-qA_0}{2m_0} \hat{\mathbf{e}} \cdot \mathbf{p}_{cv} \int_A e^{i(-\mathbf{k}_c + \mathbf{k}_v + \mathbf{k}_{op,t}) \cdot (x\hat{x} + y\hat{y})} \frac{dx dy}{A} \int_{L_z} e^{i\mathbf{k}_{op,z} \cdot z\hat{z}} \phi_n^*(z) g_m(z) dz \\
 &\simeq \frac{-qA_0}{2m_0} \hat{\mathbf{e}} \cdot \mathbf{p}_{cv} \delta_{\mathbf{k}_c, \mathbf{k}_v} \int_{L_z} \phi_n^*(z) g_m(z) dz
 \end{aligned}$$

$$\boxed{= \frac{-qA_0}{2m_0} \hat{\mathbf{e}} \cdot \mathbf{p}_{cv} \delta_{\mathbf{k}_c, \mathbf{k}_v} I_{hm}^{en}}$$

Note that here,

$$\mathbf{p}_{cv} = \langle u_c | \mathbf{p} | u_v \rangle$$

$u_c$  and  $u_v$  are Bloch functions

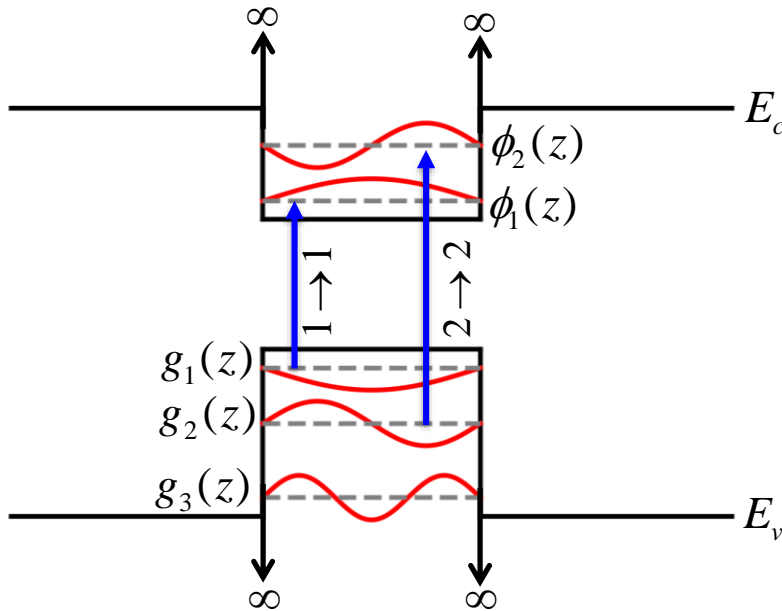


# Overlap integral

$$\hat{H}_{cv} = \frac{-qA_0}{2m_0} \hat{e} \cdot \mathbf{p}_{cv} \delta_{\mathbf{k}_c, \mathbf{k}_v} \int_{L_z} \phi_n^*(z) g_m(z) dz$$

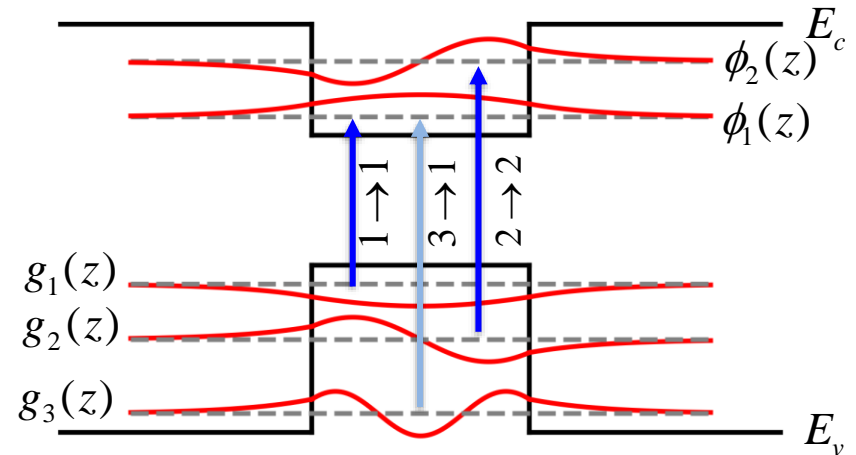
$$I_{hm}^{en} = \int_{L_z} \phi_n^*(z) g_m(z) dz$$

Infinite barrier well (approximation)



$$I_{hm}^{en} = \begin{cases} 0 & \text{for } n \neq m \\ 1 & \text{for } n=m \end{cases}$$

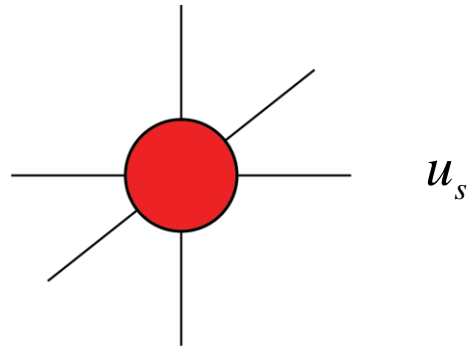
Finite barrier well



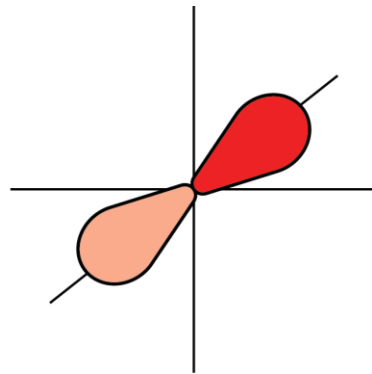
$$I_{hm}^{en} = \begin{cases} 0 & \text{for } n, m \text{ different parity} \\ \sim 1 & \text{for } n=m \\ \sim 0 & \text{for } n \neq m \text{ and } n, m \text{ same parity} \end{cases}$$

# Bloch functions $u_c$ and $u_v$

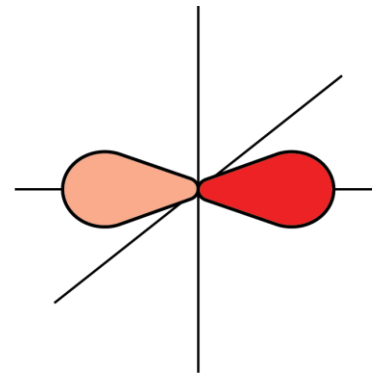
Conduction band  
Basis function



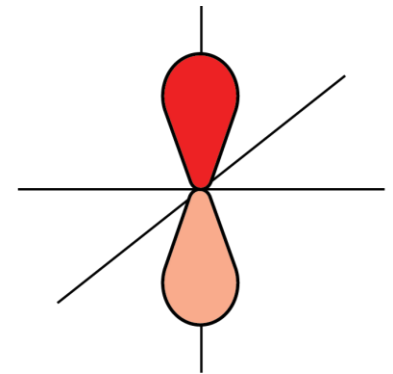
Valence band  
Basis functions



$u_x$

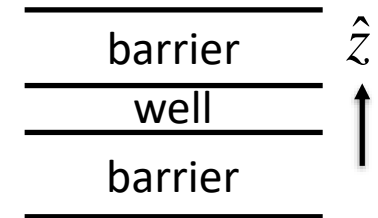


$u_y$



$u_z$

# Bloch functions $u_c$ and $u_v$



Near the bandedge the electron/hole wavevector is primarily directed in the z-direction

$$\mathbf{k}_c = \mathbf{k}_v = k_z \hat{z}$$

Below are the Bloch functions for electron wavevector in the z-direction as derived from Kane's  $k \cdot p$  model for the band structure

**Conduction band  
Bloch functions**

$$u_c = iu_s \quad \bar{u}_c = i\bar{u}_s$$

**Valence band  
Bloch functions**

$$u_{hh} = -\frac{1}{\sqrt{2}}(u_x + iu_y) \quad \bar{u}_{hh} = \frac{1}{\sqrt{2}}(\bar{u}_x - i\bar{u}_y)$$

$$u_{lh} = -\frac{1}{\sqrt{6}}(\bar{u}_x + i\bar{u}_y - 2u_z) \quad \bar{u}_{lh} = \frac{1}{\sqrt{6}}(u_x - iu_y + 2\bar{u}_z)$$

$$u_{so} = -\frac{1}{\sqrt{3}}(\bar{u}_x + i\bar{u}_y + u_z) \quad \bar{u}_{so} = \frac{1}{\sqrt{3}}(u_x - iu_y - \bar{u}_z)$$

Note: bar denotes spin-down

Reference: Chuang 4.2, Coldren App 8

# Polarization dependent matrix element

Let's calculate  $|\hat{e} \cdot \mathbf{p}_{cv}|^2$  for the **conduction band to heavy-hole band transition**

$$\begin{aligned}\hat{e} \cdot \mathbf{p}_{cv} &= \hat{e} \cdot \langle u_c | \mathbf{p} | u_v \rangle \\ &= \hat{e} \cdot \langle u_c | -i\hbar \nabla | u_v \rangle \\ &= \hat{e} \cdot \langle u_c | -i\hbar \left( \frac{\partial}{\partial x} \hat{x} + \frac{\partial}{\partial y} \hat{y} + \frac{\partial}{\partial z} \hat{z} \right) | u_v \rangle \\ &= \hat{e} \cdot \langle u_c | \mathbf{p}_x + \mathbf{p}_y + \mathbf{p}_z | u_v \rangle \\ &= \hat{e} \cdot \left\langle iu_s | \mathbf{p}_x + \mathbf{p}_y + \mathbf{p}_z \left| -\frac{1}{\sqrt{2}} (u_x + iu_y) \right\rangle\right.\end{aligned}$$

for  $\hat{e} = \hat{x}$

$$\hat{x} \cdot \mathbf{p}_{cv} = \left\langle iu_s | \mathbf{p}_x \left| -\frac{1}{\sqrt{2}} (u_x + iu_y) \right\rangle\right.$$

$$|\hat{x} \cdot \mathbf{p}_{cv}|^2 = \frac{1}{2} \left| \langle u_s | \mathbf{p}_x | u_x \rangle \right|^2 = \frac{3}{2} M_b^2$$

for  $\hat{e} = \hat{y}$

$$\hat{y} \cdot \mathbf{p}_{cv} = \left\langle iu_s | \mathbf{p}_y \left| -\frac{1}{\sqrt{2}} (u_x + iu_y) \right\rangle\right.$$

$$|\hat{y} \cdot \mathbf{p}_{cv}|^2 = \frac{1}{2} \left| \langle u_s | \mathbf{p}_y | u_y \rangle \right|^2 = \frac{3}{2} M_b^2$$

# Polarization dependent matrix element

Let's calculate  $|\hat{e} \cdot \mathbf{p}_{cv}|^2$  for the **conduction band to heavy-hole band transition**

$$\begin{aligned}\hat{e} \cdot \mathbf{p}_{cv} &= \hat{e} \cdot \langle u_c | \mathbf{p} | u_v \rangle \\ &= \hat{e} \cdot \langle u_c | -i\hbar \nabla | u_v \rangle \\ &= \hat{e} \cdot \langle u_c | -i\hbar \left( \frac{\partial}{\partial x} \hat{x} + \frac{\partial}{\partial y} \hat{y} + \frac{\partial}{\partial z} \hat{z} \right) | u_v \rangle \\ &= \hat{e} \cdot \langle u_c | \mathbf{p}_x + \mathbf{p}_y + \mathbf{p}_z | u_v \rangle \\ &= \hat{e} \cdot \langle iu_s | \mathbf{p}_x + \mathbf{p}_y + \mathbf{p}_z \left| -\frac{1}{\sqrt{2}} (u_x + iu_y) \right\rangle\end{aligned}$$

for  $\hat{e} = \hat{z}$

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$$\hat{z} \cdot \mathbf{p}_{cv} = \langle iu_s | \mathbf{p}_z \left| -\frac{1}{\sqrt{2}} (u_x + iu_y) \right\rangle = 0$$

$$|\hat{z} \cdot \mathbf{p}_{cv}|^2 = 0$$

Light with polarization in the z-direction will not cause a transition between the conduction and heavy hole band!  
(Reminder: this is at the bandedge)

# Polarization dependent matrix element

Let's calculate  $|\hat{e} \cdot \mathbf{p}_{cv}|^2$  for the **conduction band to light-hole band transition**

$$\hat{e} \cdot \mathbf{p}_{cv} = \hat{e} \cdot \left\langle iu_s \left| \mathbf{p}_x + \mathbf{p}_y + \mathbf{p}_z \right| -\frac{1}{\sqrt{6}} (\bar{u}_x + i\bar{u}_y - 2u_z) \right\rangle$$

for  $\hat{e} = \hat{x}$

$$\hat{x} \cdot \mathbf{p}_{cv} = \left\langle iu_s \left| \mathbf{p}_x \right| -\frac{1}{\sqrt{6}} (\bar{u}_x + i\bar{u}_y - 2u_z) \right\rangle$$

$$|\hat{x} \cdot \mathbf{p}_{cv}|^2 = \frac{1}{6} \left| \langle u_s \left| \mathbf{p}_x \right| u_x \rangle \right|^2 = \frac{1}{2} M_b^2$$

for  $\hat{e} = \hat{y}$

$$\hat{y} \cdot \mathbf{p}_{cv} = \left\langle iu_s \left| \mathbf{p}_y \right| -\frac{1}{\sqrt{6}} (\bar{u}_x + i\bar{u}_y - 2u_z) \right\rangle$$

$$|\hat{y} \cdot \mathbf{p}_{cv}|^2 = \frac{1}{6} \left| \langle u_s \left| \mathbf{p}_y \right| u_y \rangle \right|^2 = \frac{1}{2} M_b^2$$

for  $\hat{e} = \hat{z}$

$$\hat{z} \cdot \mathbf{p}_{cv} = \left\langle iu_s \left| \mathbf{p}_z \right| -\frac{1}{\sqrt{6}} (\bar{u}_x + i\bar{u}_y - 2u_z) \right\rangle$$

$$|\hat{z} \cdot \mathbf{p}_{cv}|^2 = \frac{2}{3} \left| \langle u_s \left| \mathbf{p}_z \right| u_z \rangle \right|^2 = 2M_b^2$$

# Momentum matrix element (bandedge)

**TE polarization**  $\hat{e} = \hat{x}$  or  $\hat{e} = \hat{y}$

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$$|\hat{e} \cdot \mathbf{p}_{c-hh}|^2 = \frac{3}{2} M_b^2 \quad (\text{heavy hole, bandedge})$$

$$|\hat{e} \cdot \mathbf{p}_{c-lh}|^2 = \frac{1}{2} M_b^2 \quad (\text{light hole, bandedge})$$

**TM polarization**  $\hat{e} = \hat{z}$

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$$|\hat{e} \cdot \mathbf{p}_{c-hh}|^2 = 0 \quad (\text{heavy hole, bandedge})$$

$$|\hat{e} \cdot \mathbf{p}_{c-lh}|^2 = 2M_b^2 \quad (\text{light hole, bandedge})$$

# Momentum matrix element (general)

$|\hat{e} \cdot \mathbf{p}_{cv}|^2$  can also be calculated “away from the bandedge” (i.e.  $k_t \neq 0$ )

**TE polarization**  $\hat{e} = \hat{x}$  or  $\hat{e} = \hat{y}$

---

$$|\hat{e} \cdot \mathbf{p}_{c-hh}|^2 = \frac{3}{4} (1 + \cos^2 \theta) M_b^2 \quad (\text{heavy hole})$$

$$|\hat{e} \cdot \mathbf{p}_{c-lh}|^2 = \left[ \frac{5}{4} - \frac{3}{4} \cos^2 \theta \right] M_b^2 \quad (\text{light hole})$$

$$\text{Note: } \cos^2 \theta = \frac{E_{en}}{E_{en} + \frac{\hbar^2 k_t^2}{2m_e^*}}$$

**TM polarization**  $\hat{e} = \hat{z}$

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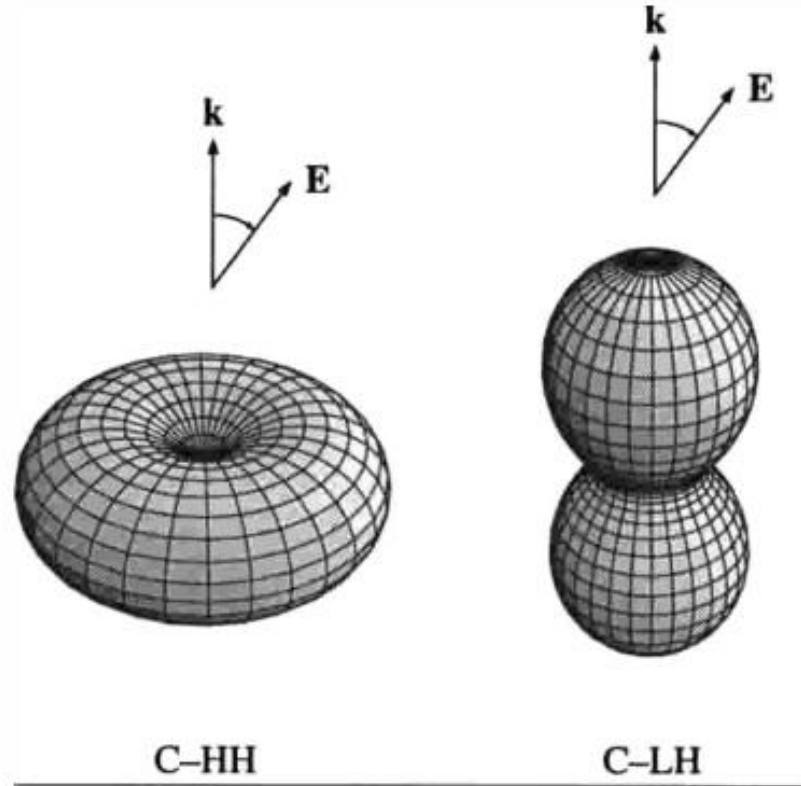
$$|\hat{e} \cdot \mathbf{p}_{c-hh}|^2 = \frac{3}{2} \sin^2 \theta M_b^2 \quad (\text{heavy hole})$$

$$|\hat{e} \cdot \mathbf{p}_{c-lh}|^2 = \frac{1}{2} (1 + 3 \cos^2 \theta) M_b^2 \quad (\text{light hole})$$



# Momentum matrix element (general)

$|\hat{e} \cdot \mathbf{p}_{cv}|^2$  can also be calculated “away from the bandedge” (i.e.  $k_t \neq 0$ )



Relative magnitude of  $M_b^2$  for conduction to heavy hole and light hole transitions.

# Summary

$$\alpha(\hbar\omega) = C_0 \frac{1}{L_z} \sum_{hh, lh} \sum_{n, m} |I_{hm}^{en}|^2 |\hat{e} \cdot \mathbf{p}_{cv}|^2 \rho_{r, 2D} H(\hbar\omega - E_{hm}^{en}) \left[ f_v(E = \hbar\omega - E_{hm}^{en}) - f_c(E = \hbar\omega - E_{hm}^{en}) \right]$$

$$\rho_{r, 2D} = \frac{m_r^*}{\pi \hbar^2}$$

$$I_{hm}^{en} = \int_{L_z} \phi_n^*(z) g_m(z) dz$$

$$\mathbf{p}_{cv} = \langle u_c | \mathbf{p} | u_v \rangle$$

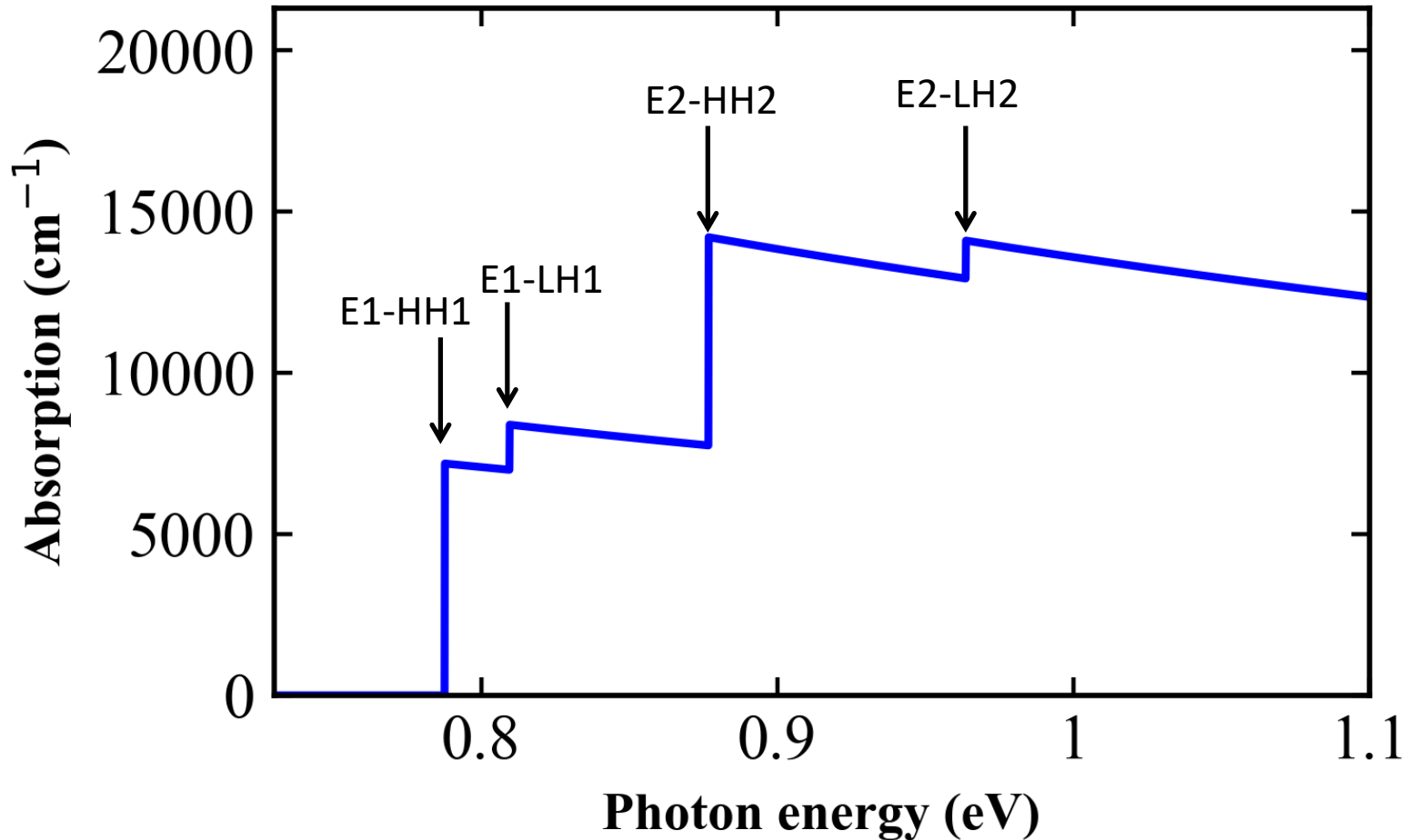
$u_c$  and  $u_v$  are bloch functions

$$C_0 = \frac{\pi q^2}{nc\epsilon_0 \omega m_0^2}$$

$$f_c(\hbar\omega) = \frac{1}{1 + \exp\left[ (E_g + E_{en} + (\hbar\omega - E_{hm}^{en}) m_r^* / m_e^* - F_c) / kT \right]}$$

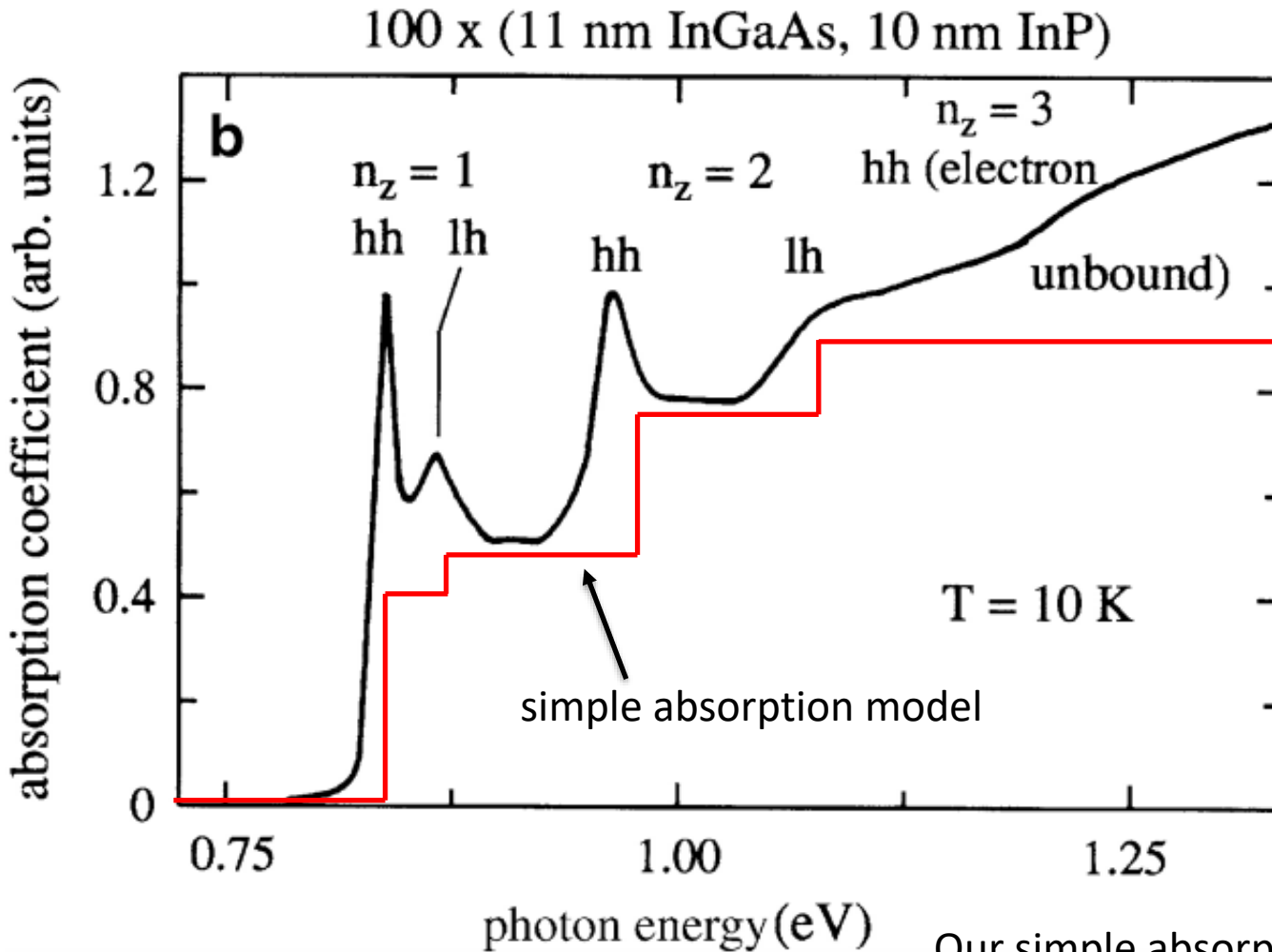
$$f_v(\hbar\omega) = \frac{1}{1 + \exp\left[ (E_{hm} - (\hbar\omega - E_{hm}^{en}) m_r^* / m_h^* - F_v) / kT \right]}$$

# Calculated absorption spectrum



InP/InGaAs quantum well ( $L_z = 11\text{nm}$ )  $T=10\text{K}$   
TE bandedge matrix elements are used

# Comparison with experimental data



Our simple absorption model does not include excitonic effects or transitions to unbound states.